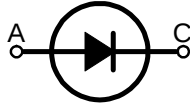
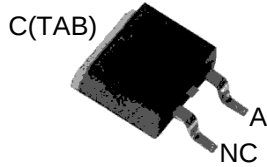
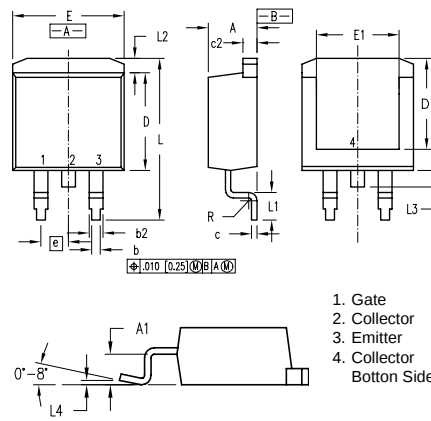


HUR820S

High-Performance Wide Temperature Range Ultra Fast Recovery Epitaxial Diode



Dimensions TO-263(D²PAK)



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	4.06	4.83	.160	.190
A1	2.03	2.79	.080	.110
b	0.51	0.99	.020	.039
b2	1.14	1.40	.045	.055
c	0.46	0.74	.018	.029
c2	1.14	1.40	.045	.055
D	8.64	9.65	.340	.380
D1	8.00	8.89	.315	.350
E	9.65	10.29	.380	.405
E1	6.22	8.13	.245	.320
e	2.54 BSC		.100 BSC	
L	14.61	15.88	.575	.625
L1	2.29	2.79	.090	.110
L2	1.02	1.40	.040	.055
L3	1.27	1.78	.050	.070
L4	0	0.20	0	.008
R	0.46	0.74	.018	.029

	V _{RSM} V	V _{RRM} V
HUR820S	200	200

Symbol	Test Conditions	Maximum Ratings	Unit
I _{FRMS} I _{FAVM}	T _C =150°C; rectangular, d=0.5	35 8	A
I _{FSM}	T _{VJ} =45°C; t _p =10ms (50Hz), sine	80	A
E _{AS}	T _{VJ} =25°C; non-repetitive; I _{AS} =2A; L=180uH	0.5	mJ
I _{AR}	V _A =1.5·V _R typ.; f=10kHz; repetitive	0.2	A
T _{VJ} T _{VJM} T _{stg}		-55...+175 175 -55...+150	°C
P _{tot}	T _C =25°C	60	W
M _d	mounting torque	0.4...0.6	Nm
Weight	typical	2	g

Sirectifier®

HUR820S

High-Performance Wide Temperature Range Ultra Fast Recovery Epitaxial Diode

Symbol	Test Conditions	Characteristic Values		Unit
		typ.	max.	
I_R	T _{VJ} =25°C; V _R =V _{RRM} T _{VJ} =150°C; V _R =V _{RRM}		50	µA
			0.2	mA
V_F	I _F =8A; T _{VJ} =150°C T _{VJ} =25°C		0.94	V
			1.30	
R_{thJC} R_{thCH}		0.5	2.5	K/W
t_{rr}	I _F =1A; -di/dt=50A/µs; V _R =30V; T _{VJ} =25°C	25		ns
I_{RM}	V _R =100V; I _F =10A; -di _F /dt=100A/µs; T _{VJ} =100°C		4.1	A

FEATURES

- * International standard package
- * Planar passivated chips
- * Very short recovery time
- * Extremely low switching losses
- * Low I_{RM}-values
- * Soft recovery behaviour

APPLICATIONS

- * Antiparallel diode for high frequency switching devices
- * Antisaturation diode
- * Snubber diode
- * Free wheeling diode in converters and motor control circuits
- * Rectifiers in switch mode power supplies (SMPS)
- * Inductive heating
- * Uninterruptible power supplies (UPS)
- * Ultrasonic cleaners and welders

ADVANTAGES

- * Avalanche voltage rated for reliable operation
- * Soft reverse recovery for low EMI/RFI
- * Low I_{RM} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Sirectifier®